

### General Description

It's mainly suitable for use as a load switch in battery powered applications.

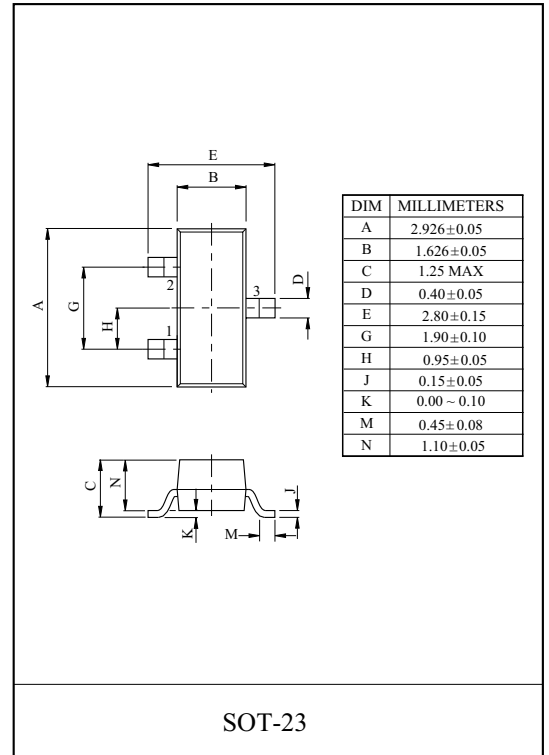
### FEATURES

- $V_{DSS}=-20V$ ,  $I_D=-2.4A$ .
- Drain-Source ON Resistance.
  - :  $R_{DS(ON)}=100m\ \Omega$  (Max.) @  $V_{GS}=-4.5V$ .
  - :  $R_{DS(ON)}=175m\ \Omega$  (Max.) @  $V_{GS}=-2.5V$ .

### MAXIMUM RATING (Ta=25 °C)

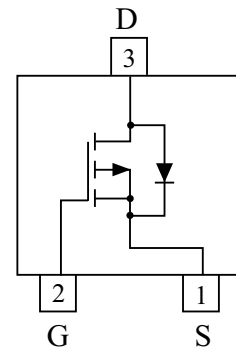
CHARACTERISTIC		SYMBOL	RATING	UNIT
Drain-Source Voltage		$V_{DSS}$	-20	V
Gate-Source Voltage		$V_{GSS}$	$\pm 12$	V
Drain Current	DC	$I_D^*$	-2.4	A
	Pulsed (Note1)	$I_{DP}^*$	-9	
Source-Drain Diode Current		$I_S^*$	-0.9	A
Drain Power Dissipation	Ta=25 °C	$P_D^*$	1.0	W
	Ta=100 °C		0.6	
Maximum Junction Temperature		$T_j$	150	°C
Storage Temperature Range		$T_{stg}$	-55 ~ 150	°C
Thermal Resistance, Junction to Ambient		$R_{thJA}^*$	125	°C/W

\* : Surface Mounted on 1" × 1" FR4 Board,  $t \leq 5sec$ .



### PIN CONNECTION

#### Top View



# KMA2D4P20S

## ELECTRICAL CHARACTERISTICS (Ta=25 °C)

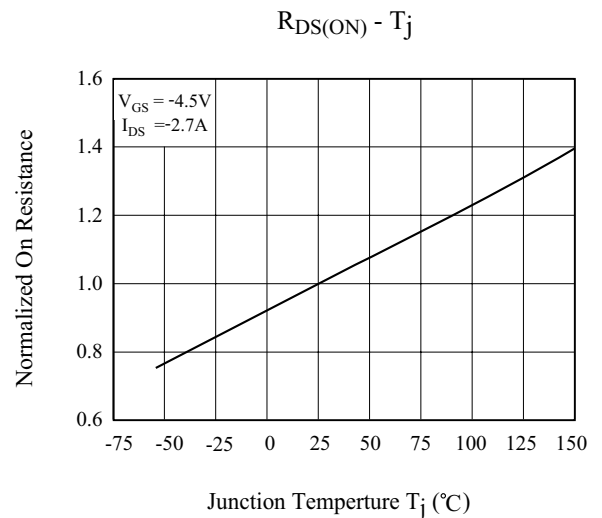
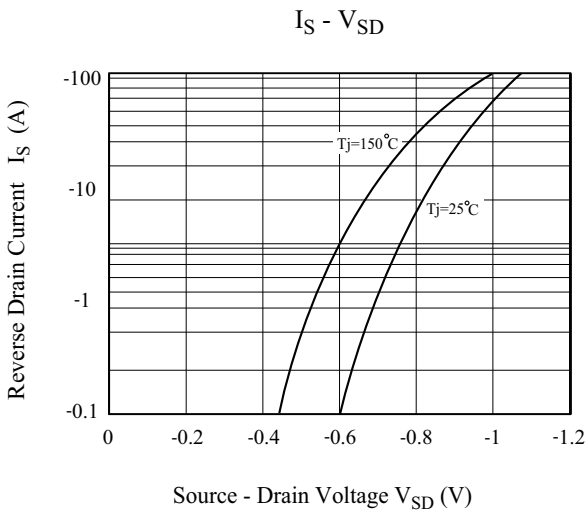
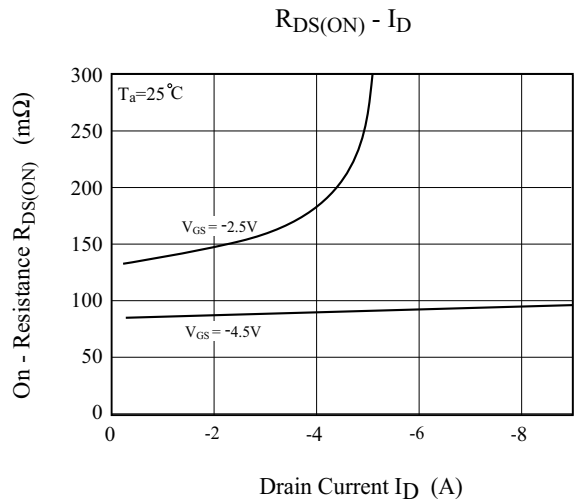
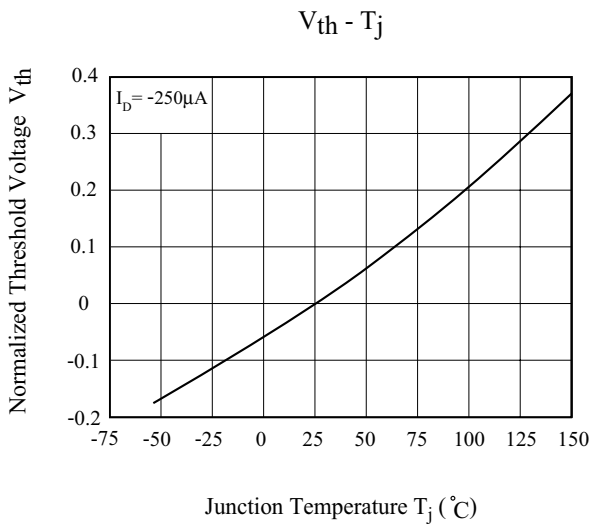
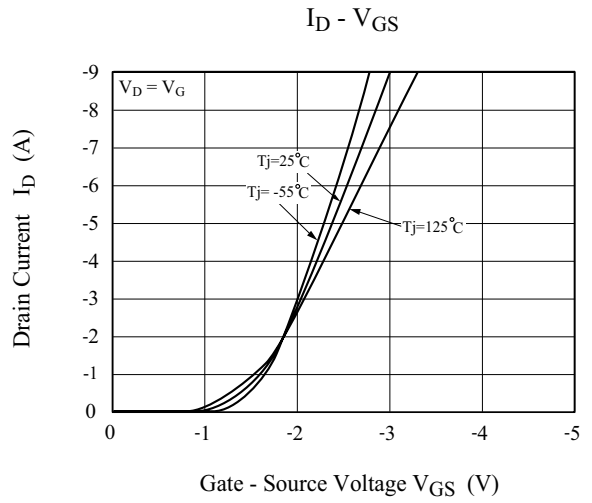
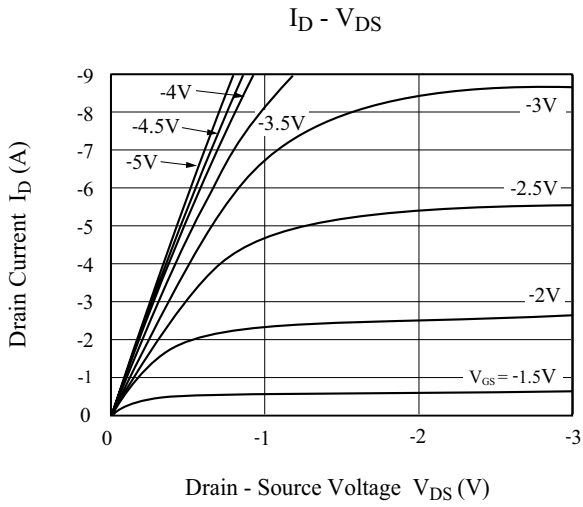
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=-250\mu A, V_{GS}=0V,$	-20	-	-	V
Drain Cut-off Current	$I_{DSS}$	$V_{GS}=0V, V_{DS}=-20V$	-	-	-1	$\mu A$
		$V_{GS}=0V, V_{DS}=-16V, T_j=70\text{ }^\circ C$	-	-	-5	
Gate Threshold Voltage	$V_{th}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.6	-	-	V
Gate Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	$\pm 100$	nA
Drain-Source ON Resistance	$R_{DS(ON)}$	$V_{GS}=-4.5V, I_D=-2.4A$ (Note 1)	-	88	100	m $\Omega$
		$V_{GS}=-2.5V, I_D=-1.8A$ (Note 1)	-	146	175	
ON State Drain Current	$I_{D(ON)}$	$V_{GS}=-4.5V, V_{DS}=-5V$ (Note 1)	-9	-	-	A
Forward Transconductance	$g_{fs}$	$V_{DS}=-5V, I_D=-2.4A$ (Note 1)	-	4	-	S
Source-Drain Diode Forward Voltage	$V_{SD}$	$I_S=-2.4A, V_{GS}=0V$ (Note 1)	-	-	-1.3	V
<b>Dynamic (Note 2)</b>						
Total Gate Charge	$Q_g$	$V_{DS}=-15V, R_D=5.6\ \Omega$ $V_{GS}=-4.5V$ (Fig.1)	-	4	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.6	-	
Gate-Drain Charge	$Q_{gd}$		-	1.4	-	
Turn-on Delay time	$t_{d(on)}$	$V_{DS}=-15V, R_L=5.6\ \Omega,$ $V_{GS}=-4.5V, R_G=6\ \Omega$ (Fig.2)	-	6.5	-	ns
Turn-on Rise time	$t_r$		-	13	-	
Turn-off Delay time	$t_{d(off)}$		-	15	-	
Turn-off Fall time	$t_f$		-	20	-	

Note 1) Pulse test : Pulse width  $\leq 300\ \mu s$ , Duty Cycle  $\leq 2\%$ .

Note 2) Guaranteed by design. Not subject to production testing.

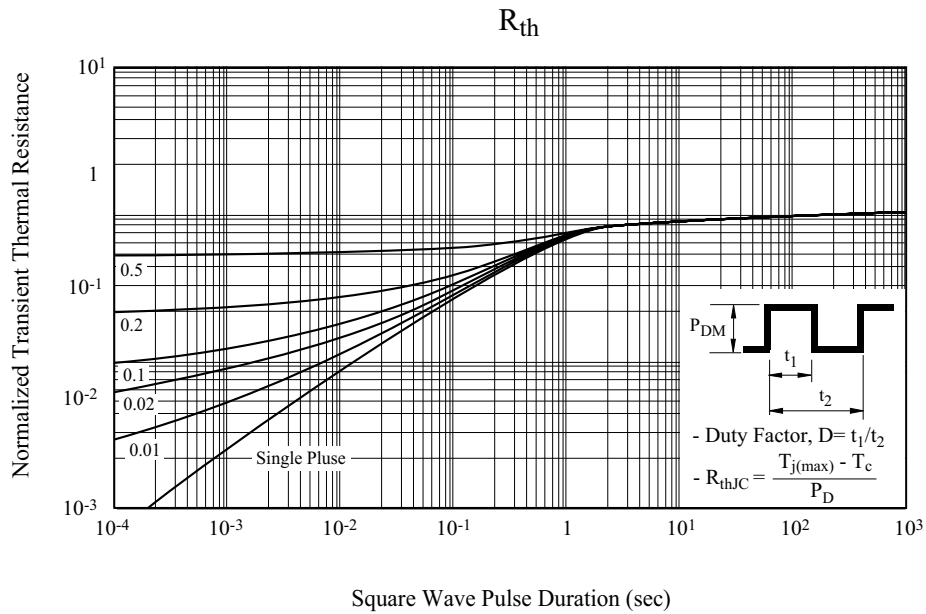
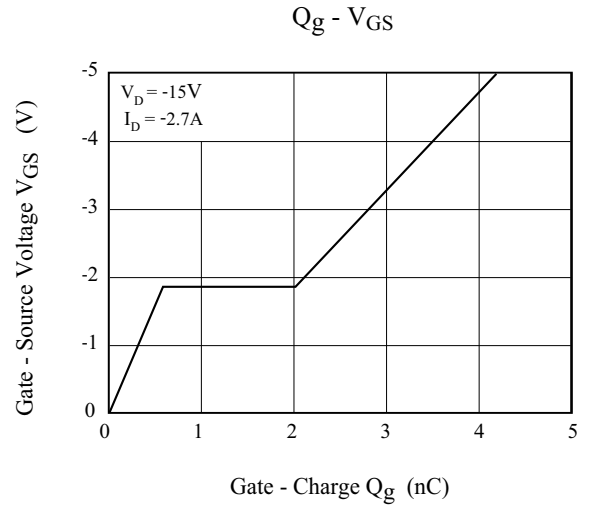
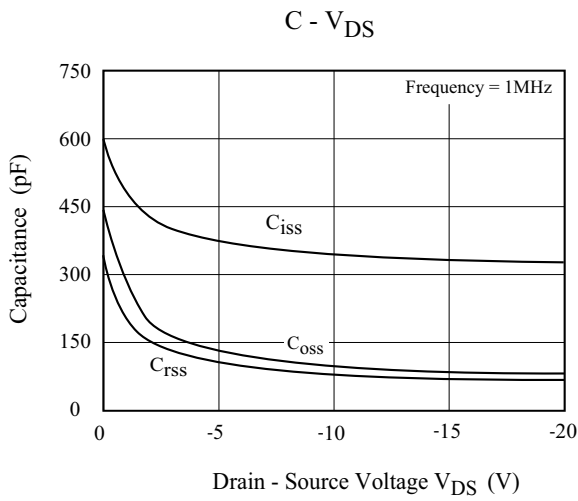
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Fig. 1 Gate Charge

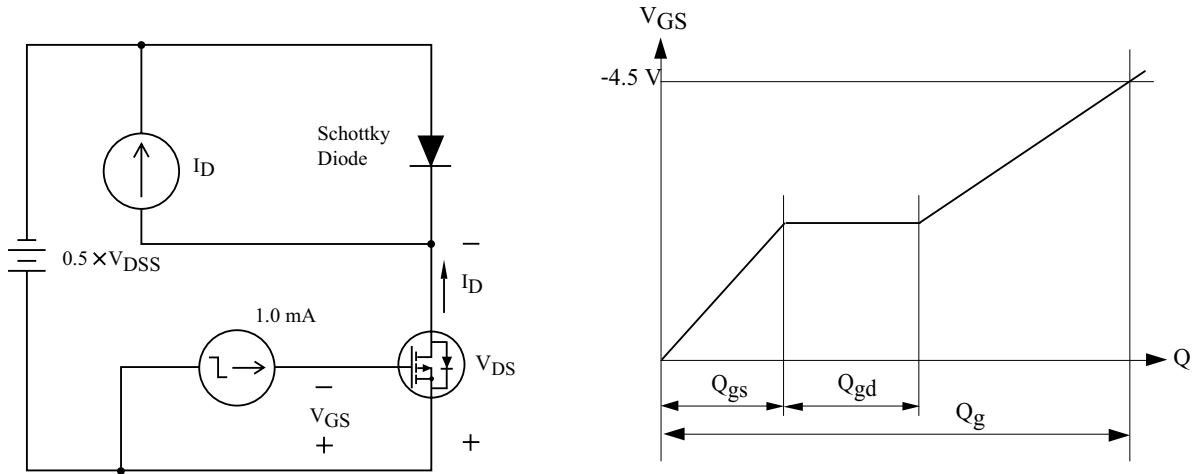


Fig. 2 Resistive Load Switching

